

## Features

- Operated at Low Logic Level Gate Drive
- P-Channel Switch with Low  $R_{DS(on)}$
- Epoxy Meets UL 94 V-0 Flammability Rating
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note 1)
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

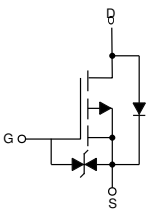
## Maximum Ratings

- Operating Junction Temperature Range:  $-55^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$
- Storage Temperature Range:  $-55^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$
- Maximum Thermal Resistance:  $138^{\circ}\text{C/W}$  Junction to Ambient

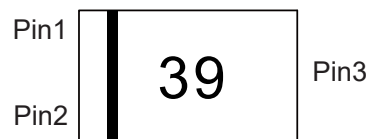
| Parameter                               | Symbol   | Rating   | Unit |
|---|----------|----------|------|
| Drain-Source Voltage                    | $V_{DS}$ | -20      | V    |
| Gate-Source Voltage                     | $V_{GS}$ | $\pm 12$ | V    |
| Drain Current-Continuous <sup>(2)</sup> | $I_D$    | -0.65    | A    |
| Pulsed Drain Current                    | $I_{DM}$ | -2       | A    |
| Power Dissipation <sup>(3)</sup>        | $P_D$    | 0.9      | W    |

Note: 1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

## Internal Structure and Marking Code

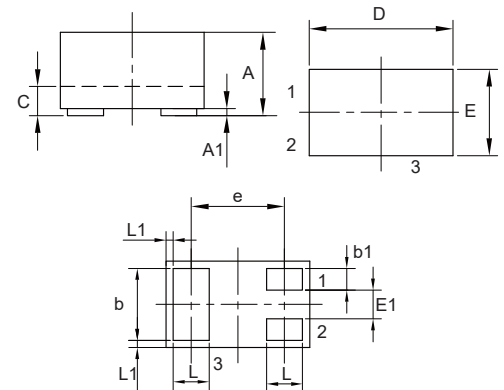


1. GATE
2. SOURCE
3. DRAIN



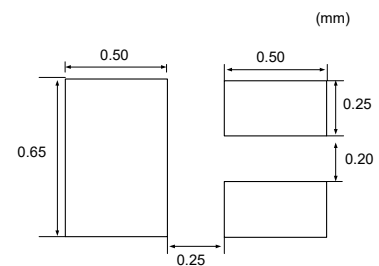
## P-Channel MOSFET

### DFN1006-3



| DIM | INCHES |       | MM   |      | NOTE |
|-----|--------|-------|------|------|------|
|     | MIN    | MAX   | MIN  | MAX  |      |
| A   | 0.017  | 0.022 | 0.42 | 0.55 |      |
| A1  | 0.000  | 0.002 | 0.00 | 0.05 |      |
| b   | 0.018  | 0.022 | 0.45 | 0.55 |      |
| b1  | 0.004  | 0.008 | 0.10 | 0.20 |      |
| c   | 0.005  | 0.007 | 0.12 | 0.18 |      |
| D   | 0.037  | 0.041 | 0.95 | 1.05 |      |
| E   | 0.022  | 0.026 | 0.55 | 0.65 |      |
| E1  | 0.006  | 0.010 | 0.15 | 0.25 |      |
| e   | 0.026  |       | 0.65 |      | TYP. |
| L   | 0.008  | 0.012 | 0.20 | 0.30 |      |
| L1  | 0.0002 |       | 0.05 |      | TYP. |

### Suggested Solder Pad Layout



**ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

| Parameter   | Symbol        | Test conditions                                       | Min   | Typ   | Max      | Unit     |
|---|---------------|---|-------|-------|----------|----------|
| <b>Static Characteristics</b>                       |               |   |       |       |          |          |
| Drain-Source Breakdown Voltage                      | $V_{(BR)DSS}$ | $V_{GS}=0V, I_D=-250\mu A$                            | -20   |       |          | V        |
| Gate-Threshold Voltage <sup>(Note 2)</sup>          | $V_{GS(th)}$  | $V_{DS}=V_{GS}, I_D=-250\mu A$                        | -0.35 | -0.62 | -1.2     | V        |
| Zero Gate Voltage Drain Current                     | $I_{DSS}$     | $V_{DS}=-20V, V_{GS}=0V$                              |       |       | -1.0     | $\mu A$  |
| Gate-body Leakage Current                           | $I_{GSS}$     | $V_{GS}=\pm 10V, V_{DS}=0V$                           |       |       | $\pm 10$ | $\mu A$  |
| Drain-Source On-Resistance <sup>(Note 2)</sup>      | $R_{DS(on)}$  | $V_{GS}=-4.5V, I_D=-500mA$                            |       | 0.58  | 0.85     | $\Omega$ |
|   |               | $V_{GS}=-2.5V, I_D=-300mA$                            |       | 0.86  | 1.2      |          |
|   |               | $V_{GS}=-1.8V, I_D=-200mA$                            |       | 1.35  | 2.0      |          |
| Forward transconductance                            | $g_{FS}$      | $V_{DS}=-10V, I_D=-500mA$                             | 0.8   |       |          | S        |
| Diode Forward Voltage <sup>(Note 2)</sup>           | $V_{SD}$      | $V_{GS}=0V, I_S=-650mA$                               |       |       | -1.2     | V        |
| <b>Dynamic Characteristics<sup>(Note 3)</sup></b>   |               |   |       |       |          |          |
| Input Capacitance                                   | $C_{iss}$     | $V_{DS}=-16V, V_{GS}=0V, f=1MHz$                      |       | 40    |          | pF       |
| Output Capacitance                                  | $C_{oss}$     |   |       | 16    |          |          |
| Reverse Transfer Capacitance                        | $C_{rss}$     |   |       | 11    |          |          |
| Total Gate Charge                                   | $Q_g$         | $V_{GS}=-4.5V, V_{DS}=-10V, I_D=-1A$                  |       | 860   |          | pC       |
| Gate-Source Charge                                  | $Q_{gs}$      |   |       | 320   |          |          |
| Gate-Drain Charge                                   | $Q_{gd}$      |   |       | 200   |          |          |
| <b>Switching Characteristics<sup>(Note 3)</sup></b> |               |   |       |       |          |          |
| Turn-on Delay Time                                  | $t_{d(on)}$   | $V_{DS}=-10V, V_{GS}=-4.5V, I_D=-500mA, R_G=10\Omega$ |       | 3.8   |          | ns       |
| Turn-off Delay Time                                 | $t_{d(off)}$  |   |       | 9.4   |          |          |
| Rise Time   | $t_r$         |   |       | 19    |          |          |
| Fall Time   | $t_f$         |   |       | 23    |          |          |

**Notes :**

- Pulse Test : Pulse Width $\leq 300\mu s$ , Duty Cycle $\leq 0.5\%$ .
- Guaranteed by Design, Not Subject to Production Testing.

## Curve Characteristics

Fig. 1 - Typical Output Characteristics

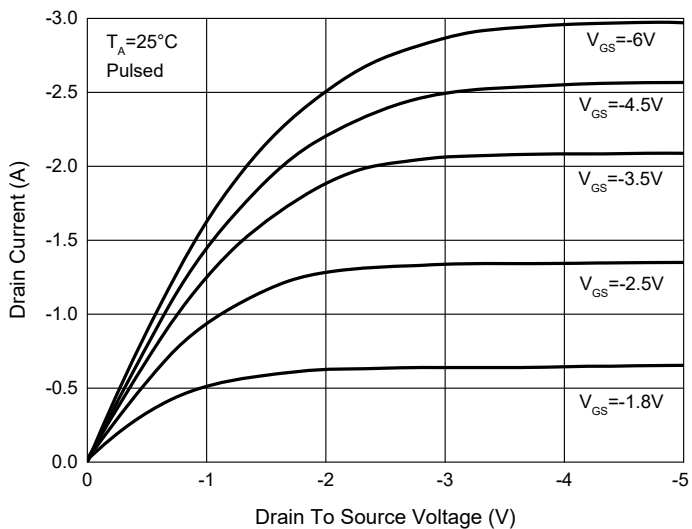


Fig. 2 - Transfer Characteristics

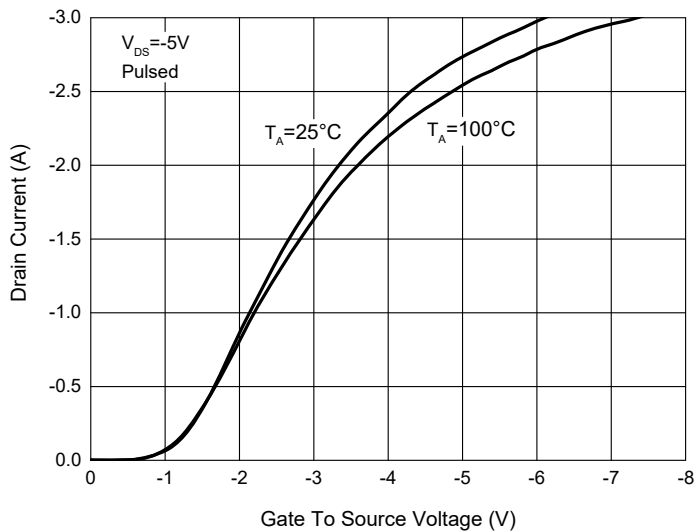


Fig. 3 -  $R_{DS(ON)} - I_D$

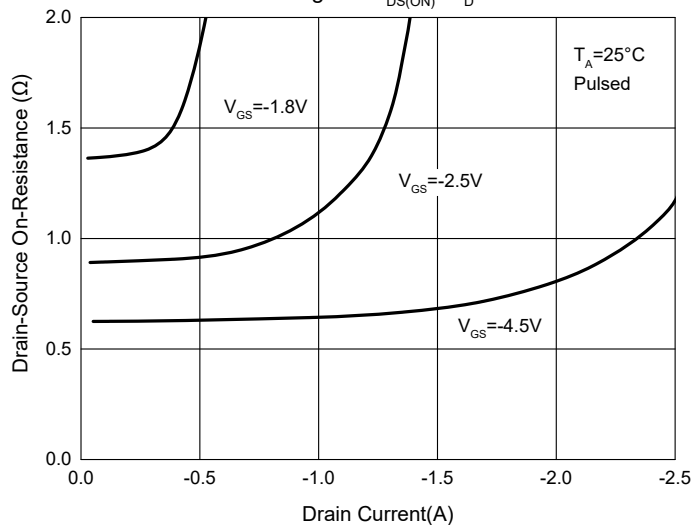


Fig. 4 -  $R_{DS(ON)} - V_{GS}$

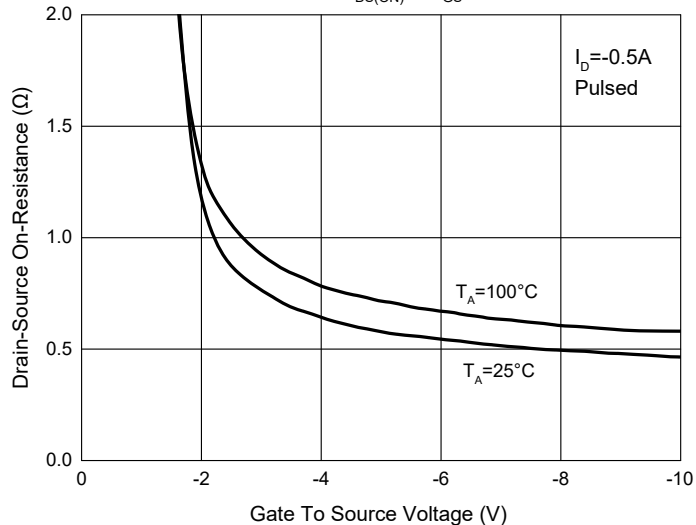


Fig. 5 -  $I_S - V_{SD}$

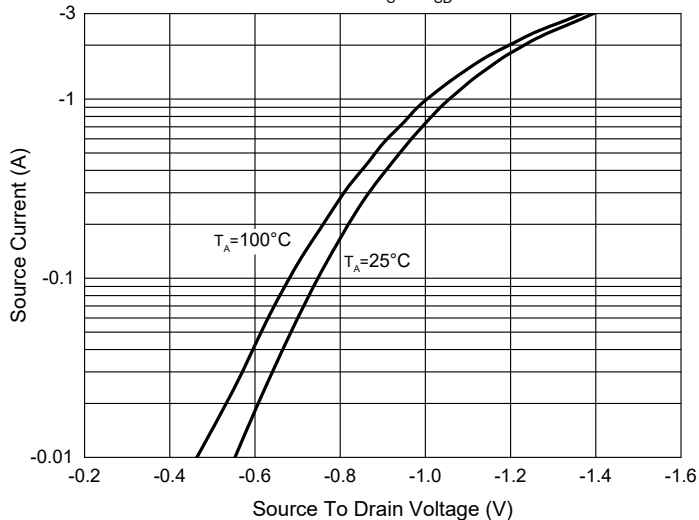
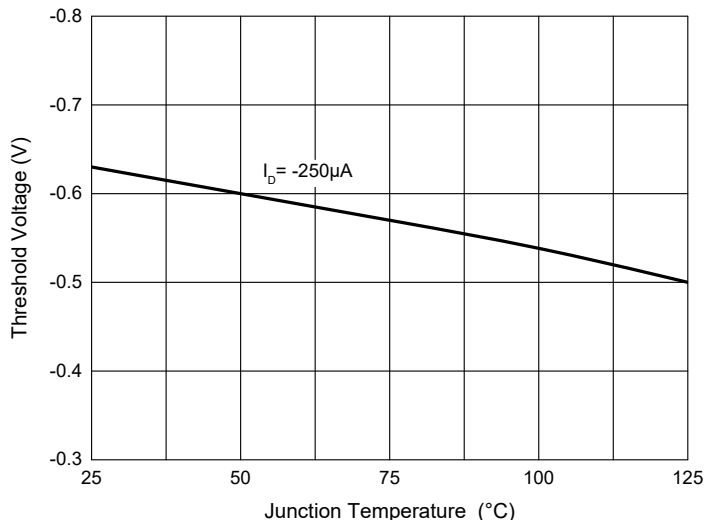


Fig. 6 - Threshold Voltage



## Curve Characteristics

Fig. 7 - Capacitance Characteristics

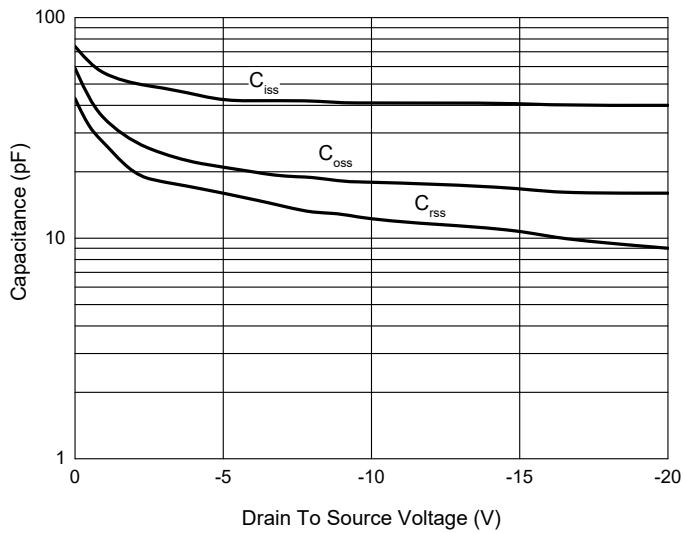
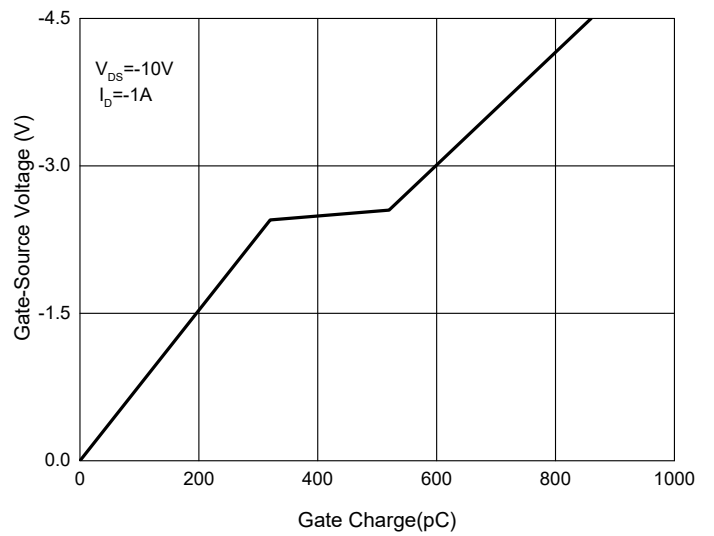


Fig. 8 - Gate Charge



## Ordering Information

| Device         | Packing               |
|----------------|-----------------------|
| Part Number-TP | Tape&Reel:10Kpcs/Reel |

**\*\*\*IMPORTANT NOTICE\*\*\***

*Micro Commercial Components Corp.* reserves the right to make changes without further notice to any product herein to make corrections, modifications, enhancements, improvements, or other changes. *Micro Commercial Components Corp.* does not assume any liability arising out of the application or use of any product described herein; neither does it convey any license under its patent rights, nor the rights of others. The user of products in such applications shall assume all risks of such use and will agree to hold *Micro Commercial Components Corp.* and all the companies whose products are represented on our website, harmless against all damages. *Micro Commercial Components Corp.* products are sold subject to the general terms and conditions of commercial sale, as published at <https://www.mccsemi.com/Home/TermsAndConditions>.

**\*\*\*LIFE SUPPORT\*\*\***

MCC's products are not authorized for use as critical components in life support devices or systems without the express written approval of Micro Commercial Components Corporation.

**\*\*\*CUSTOMER AWARENESS\*\*\***

Counterfeiting of semiconductor parts is a growing problem in the industry. Micro Commercial Components (MCC) is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. MCC strongly encourages customers to purchase MCC parts either directly from MCC or from Authorized MCC Distributors who are listed by country on our web page cited below. Products customers buy either from MCC directly or from Authorized MCC Distributors are genuine parts, have full traceability, meet MCC's quality standards for handling and storage. **MCC will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources.** MCC is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.